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Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All recreations are done with the approval of the OCM.

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceed the OCM data sheet.

## **Quality Overview**

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-35835
  - Class Q Military
  - Class V Space Level
- Qualified Suppliers List of Distributors (QSLD)

• Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OEM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.



# LM185/LM285/LM385 Adjustable Micropower Voltage References

### **General Description**

The LM185/LM285/LM385 are micropower 3-terminal adjustable band-gap voltage reference diodes. Operating from 1.24 to 5.3V and over a 10 $\mu$ A to 20mA current range, they feature exceptionally low dynamic impedance and good temperature stability. On-chip trimming is used to provide tight voltage tolerance. Since the LM185 band-gap reference uses only transistors and resistors, low noise and good long-term stability result.

Careful design of the LM185 has made the device tolerant of capacitive loading, making it easy to use in almost any reference application. The wide dynamic operating range allows its use with widely varying supplies with excellent regulation.

The extremely low power drain of the LM185 makes it useful for micropower circuitry. This voltage reference can be used to make portable meters, regulators or general purpose analog circuitry with battery life approaching shelf life. Further, the wide operating current allows it to replace older references with a tighter tolerance part.

The LM185 is rated for operation over a  $-55^{\circ}$ C to  $125^{\circ}$ C temperature range, while the LM285 is rated  $-40^{\circ}$ C to  $85^{\circ}$ C and the LM385 0°C to 70°C. The LM185 is available in a hermetic TO-46 package and a leadless chip carrier package, while the LM285/LM385 are available in a low-cost TO-92 molded package, as well as S.O.

### **Features**

- Adjustable from 1.24V to 5.30V
- Operating current of 10µA to 20mA
- 1% and 2% initial tolerance
- 1Ω dynamic impedance
- Low temperature coefficient

## **Connection Diagrams**



ile the nolded M185/LM285/LM385 Adjustable Micropower Voltage Reference

# LM185/LM285/LM385

# Ordering Information

Package		Temperature Range		NSC Drawing
–55°C to 125°C	–40°C to 85°C	0°C to 70°C		
	LM185BH			
	LM185BH/883			Цорц
10-40	LM185BYH			- HU3H
	LM185BYH/883			
		LM285BXZ	LM385BXZ	
TO 02		LM285BYZ	LM385BYZ	7024
10-92		LM285Z	LM385BZ	203A
			LM385Z	
		LM285M	LM385M	14004
8-Pin SOIC		LM285BYM	LM385BM	M08A
20-Leadless Chip Carrier	LM185BE/883			E20A

# **Block Diagram**



# **Typical Applications**



5.0V Reference





# LM185/LM285/LM385

2kV

260°C 300°C

215°C

220°C

-55°C to 150°C

## Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

(Note 2)		TO-46 Package (10 sec.)	300°0
Reverse Current	30mA	SO Package	
Forward Current	10mA	Vapor Phase (60 sec.)	215°C
Operating Temperature Range (Note 3)	i oni i t	Infrared (15 sec.)	220°C
LM185 Series	–55°C to 125°C	See An-450 "Surface Mounting Methods	s and Their Effect
LM285 Series	–40°C to 85°C	surface mount devices	s of soldering
LM385 Series	0°C to 70°C		

### Electrical Characteristics (Note 4)

		LM185, LM285					LM385					
Paramotor	Conditions	Тур	LM185BX, LM185BY LM185B, LM285BX, LM285BY		LM285			LM385BX, LM385BY		LM385		Units
Falameter	Conditions						Тур					(Limit)
			Tested	Design	Tested	Design		Tested	Design	Tested	Design	
			Limit	Limit	Limit	Limit		Limit	Limit	Limit	Limit	
			(Note	(Note	(Note	(Note		(Note	(Note	(Note	(Note	
			5)	6)	5)	6)		5)	6)	5)	6)	
Reference Voltage	Ι <sub>R</sub> = 100μΑ	1.240	1.252		1.265	1.270	1.240	1.252	1.255	1.265	1.270	V
			1.255									(max)
			1.228		1.215	1.205		1.228	1.215	1.215	1.205	V
			1.215									(min)
Reference Voltage	I <sub>MIN</sub> < I <sub>R</sub> < 1mA	0.2	1	1.5	1	1.5	0.2	1	1.5	1	1.5	mV
Change with Current	1mA < I <sub>R</sub> < 20mA	4	10	20	10	20	5	15	25	15	25	(max)
Dynamic Output	I <sub>R</sub> = 100μA, f = 100Hz											
Impedance	$I_{AC} = 0.1 I_R$ $V_{OUT} = V_{BFF}$	0.3					0.4					Ω
	V <sub>OUT</sub> = 5.3V	0.7					1					
Reference	Ι <sub>R</sub> = 100μΑ											mV
Voltage												
Change with		1	3	6	3	6	2	5	10	5	10	(max)
Output												
Voltage												<u> </u>
Feedback		13	20	25	20	25	16	30	35	30	35	nA (max)
Minimum		6		10	0	10	7	11	10		10	(max)
Operating	V <sub>OUT</sub> = V <sub>REF</sub>	0	9	10	9	10	'		13	11	13	μΑ
Current (see	V= 5.3V	30	45	50	45	50	35	55	60	55	60	(max)
curve)	V <sub>OUT</sub> = 0.0V	00			-10				00	00	00	
Output	I <sub>D</sub> = 100µA, 10Hz < f <				·							
Wideband	10kHz											
Noise	V <sub>OUT</sub> = V <sub>BEE</sub>	50					50					μV
	$V_{OUT} = 5.3V$	170					170					' ms
		-	I	1		I		I	<u> </u>	<u> </u>		I

ESD Susceptibility (Note 8)

TO-92 Package (10 sec.)

Storage Temperature

Soldering Information

	Parameter Conditions Ty		LM185, LM285					LM385					
				LM185BX, LM185BY LM185B, LM285BX, LM285BY		LM285			LM38	LM385BX, LM385BY		LM385	
Parameter			Тур					Тур					(Limit)
				Tested	Design	Tested	Design		Tested	Design	Tested	Design	
				Limit	Limit	Limit	Limit		Limit	Limit	Limit	Limit	
				(Note	(Note	(Note	(Note		(Note	(Note	(Note	(Note	
				5)	6)	5)	6)		5)	6)	5)	6)	
Average Temperature	Ι <sub>R</sub> = 100μΑ	X Suffix		30					30				ppm/° c
Coefficient		Y Suffix		50					50				(max)
(Note 7)													
		All Others			150		150			150		150	
Long Term Stability	I <sub>R</sub> = 100µA, 1 Hr,	Γ = 1000	20					20					ppm
	$T_A = 25^{\circ}C \pm 0$	0.1°C											

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed.

150°C

Note 2: Refer to RETS185H for military specifications.

Note 3: For elevated temperature operation, T<sub>1</sub>max is:

LM28	5 125°C		
LM38	5 100°C		
Thermal Resistance	TO-92	TO-46	SO-8
$\theta_{JA}$ (Junction to Ambient)	180°C/W (0.4 leads)	440°C/W	165°C/W
	170°C/W (0.125 leads)		
$\theta_{JC}$ (Junction to Case)	N/A	80°C/W	N/A

Note 4: Parameters identified with **boldface type** apply at temperature extremes. All other numbers apply at  $T_A = T_J = 25^{\circ}C$ . Unless otherwise specified, all parameters apply for  $V_{REF} < V_{OUT} < 5.3V$ .

Note 5: Guaranteed and 100% production tested.

Note 6: Guaranteed, but not 100% production tested. These limits are not to be used to calculate average outgoing quality levels.

LM185

Note 7: The average temperature coefficient is defined as the maximum deviation of reference voltage at all measured temperatures from  $T_{MIN}$  to  $T_{MAX}$ , divided by  $T_{MAX} - T_{MIN}$ . The measured temperatures are -55, -40, 0, 25, 70, 85, 125°C.

Note 8: The human body model is a 100 pF capacitor discharged through a 1.5 k $\Omega$  resistor into each pin.



### **Typical Performance Characteristics Temperature Drift of 3 Representative Units** 1.260 **REFERENCE VOLTAGE (V)** 1.250 1.240 1.230 1.220 25 45 65 85 105 125 - 55 - 35 - 15 5 **TEMPERATURE (°C)** 525016 **Minimum Operating Current** 80 70 WORST MINIMUM CURRENT (µA) 60 CASE LM385 50 WORST 40 CASE LM185 30 20 TYP @ 25°C 10 0 2 6 1 3 4 5 `` **OUTPUT VOLTAGE (V)** 525018 **Reverse Characteristics** 10 T I FIIH **VREF** Vouț **OUTPUT VOLTAGE CHANGE (mV)** 8 6 4 2 0 - 2 0.01 0.1 10 100 1 **REVERSE CURRENT (mA)** 525020





# **Typical Applications**





### 25V Low Current Shunt Regulator



525027



### 200 mA Shunt Regulator





LM185/LM285/LM385



\*D1 can be any LED, V<sub>F</sub>=1.5V to 2.2V at 3 mA. D1 may act as an indicator. D1 will be on if I<sub>THRESHOLD</sub> falls below the threshold current, except with I=O.





**Schematic Diagram** 







# Notes

# Notes

Pr	oducts	Design Support					
Amplifiers	www.national.com/amplifiers	WEBENCH	www.national.com/webench				
Audio	www.national.com/audio	Analog University	www.national.com/AU				
Clock Conditioners	www.national.com/timing	App Notes	www.national.com/appnotes				
Data Converters	www.national.com/adc	Distributors	www.national.com/contacts				
Displays	www.national.com/displays	Green Compliance	www.national.com/quality/green				
Ethernet	www.national.com/ethernet	Packaging	www.national.com/packaging				
Interface	www.national.com/interface	Quality and Reliability	www.national.com/quality				
LVDS	www.national.com/lvds	Reference Designs	www.national.com/refdesigns				
Power Management	www.national.com/power	Feedback	www.national.com/feedback				
Switching Regulators	www.national.com/switchers						
LDOs	www.national.com/ldo						
LED Lighting	www.national.com/led						
PowerWise	www.national.com/powerwise						
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